

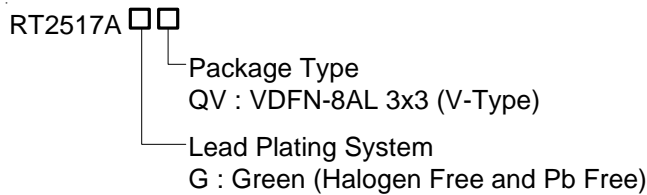
1A, 6V, Ultra Low Dropout Linear Regulator

General Description

The RT2517A is a high performance positive voltage regulator designed for applications requiring low input voltage and ultra low dropout voltage at up to 1A. The feature of ultra low dropout voltage is ideal for applications where output voltage is very close to input voltage. The input voltage can be as low as 2.2V and the output voltage is adjustable by an external resistive divider. The RT2517A provides an excellent output voltage regulation over variations in line, load and temperature. Current limit and thermal shutdown functions are provided. Additionally, an enable pin is designed to further reduce power consumption while shutdown and the shutdown current is as low as 0.1µA.

The RT2517A is available in the VDFN-8AL 3x3 package.

Ordering Information



Note :

Richtek products are :

- ▶ RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
- ▶ Suitable for use in SnPb or Pb-free soldering processes.

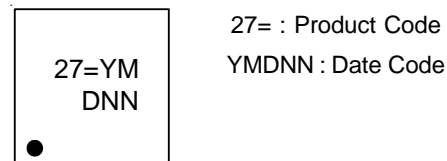
Features

- Input Voltage Range : 2.2V to 6V
- V_{OUT} Range from 1.2V to V_{IN} - V_{DROP}
- Reference Voltage : 1.2V ±2.5% over -40°C to 85°C
- Ultra Low Dropout Voltage : 150mV at 1A over -40°C to 85°C
- Low Quiescent 0.1µA in Shutdown Mode
- Soft-Discharge Function
- Thermal Shutdown and Current Limit

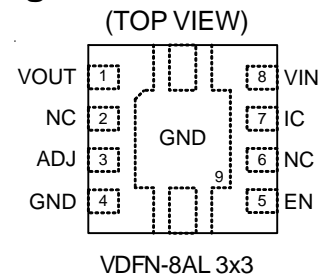
Applications

- Automotive Audio, Navigation, & Info systems
- Industrial Grade General Purpose Point of Load
- Digital Set top Boxes
- Vehicle Electronics

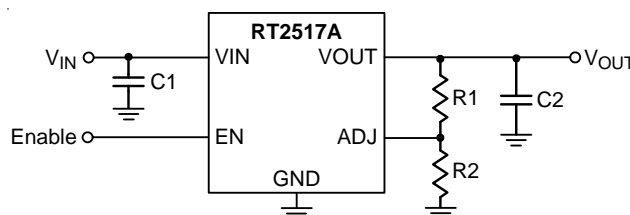
Marking Information



Pin Configuration



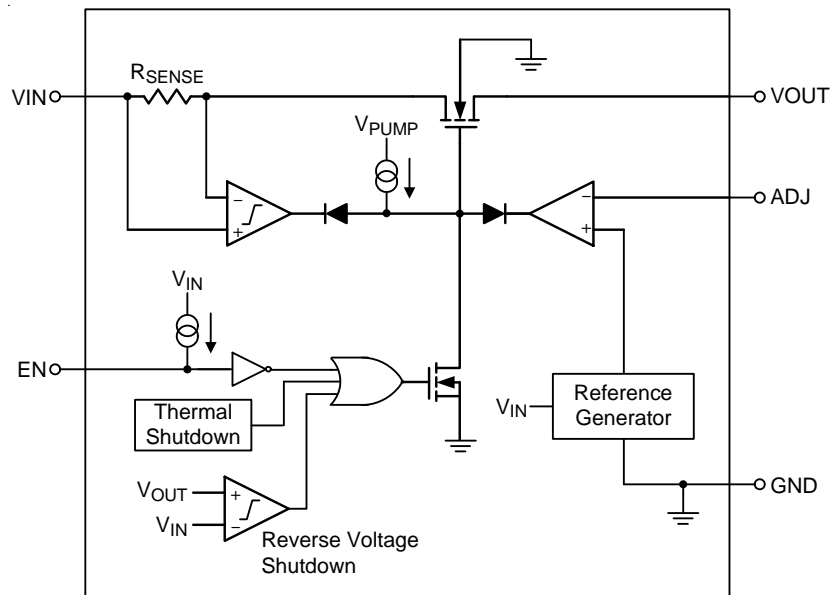
Simplified Application Circuit



Functional Pin Description

Pin No.	Pin Name	Pin Function
1	VOUT	Output voltage. A minimum 10 μ F capacitor should be placed directly at this pin.
2, 6	NC	No internal connection.
3	ADJ	Feedback voltage input. Connect an external resistor divider to this pin for output voltage setting. If this pin is connected to the VOUT pin, the output voltage will be set at 1.2V.
4, 9 (Exposed pad)	GND	Ground. The exposed pad must be soldered to a large PCB and connected to GND for maximum the power dissipation.
5	EN	Enable control input (Active High). This pin will be pulled up by internal circuit if this pin is open.
7	IC	Internal connection. Leave floating and do not make connection to this pin.
8	VIN	Supply voltage input. Connect a minimum 10 μ F ceramic capacitor at this pin.

Functional Block Diagram



Operation

The RT2517A is a low input voltage low dropout LDO that can support the input voltage range from 1.4V to 6V and the output current can be up to 1A. The RT2517A uses internal charge pump to achieve low input voltage operation and the internal compensation network is well designed to achieve fast transient response with good stability.

In steady-state operation, the feedback voltage is regulated to the reference voltage by the internal regulator. When the feedback voltage signal is less than the reference, the on resistance of the power MOSFET is decreased to increase the output current through the power MOSFET, and the feedback voltage will be charge back to reference. If the feedback voltage is less than the reference, the power MOSFET current is decreased to make the output voltage discharge back to reference by the loading current.

Reverse Current Protection

The reverse current protection is guaranteed by the N-MOSFET with bulk capacitors connected to GND and the internal circuit. The reverse voltage detection circuit shuts the total loop down if the output voltage is higher than input voltage.

Output Under-Voltage Protection (UVP) and Over-Current Fold-Back

When the feedback voltage is lower than 0.15V after internal soft-start end, the UVP is triggered. If the over-current condition is triggered during UVP state, the OC limit current will be decreased to limit the output power and change into re-soft start state at the same time.

Soft-Start

An internal current source charges an internal capacitor to build the soft-start ramp voltage. The typical soft-start time is 150 μ s. During the soft-start state, the output current will be limited to prevent the inrush current.

Over-Temperature Protection (OTP)

The RT2517A has an over-temperature protection. When the device triggers the OTP, the device shuts down until the temperature back to normal and move to re-soft start state.

Absolute Maximum Ratings (Note 1)

- Supply Voltage, V_{IN} ----- -0.3V to 7V
- Other Pins ----- -0.3V to 6V
- Power Dissipation, P_D @ $T_A = 25^\circ\text{C}$
 VDFN-8AL 3x3 ----- 1.667W
- Package Thermal Resistance (Note 2)
 VDFN-8AL 3x3, θ_{JA} ----- 60°C/W
 VDFN-8AL 3x3, θ_{JC} ----- 7°C/W
- Lead Temperature (Soldering, 10 sec.) ----- 260°C
- Junction Temperature ----- 150°C
- Storage Temperature Range ----- -65°C to 150°C
- ESD Susceptibility (Note 3)
 HBM (Human Body Model) ----- 2kV
 CDM (Charged Device Model) ----- 1kV
 MM (Machine Model) ----- 200V

Recommended Operating Conditions (Note 4)

- Supply Input Voltage, V_{IN} ----- 2.2V to 6V
- Junction Temperature Range ----- -40°C to 125°C
- Ambient Temperature Range ----- -40°C to 85°C

Electrical Characteristics

($V_{IN} = 2.2\text{V}$ to 6V , $I_{OUT} = 10\mu\text{A}$ to 1A , $V_{ADJ} = V_{OUT}$, $-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Output Voltage	V_{OUT}	$V_{IN} = 3.3\text{V}$, $T_A = 25^\circ\text{C}$	-1	--	1	%
		$2.2\text{V} \leq V_{IN} \leq 6\text{V}$, $10\text{mA} \leq I_{OUT} \leq 1\text{A}$	-2.5	--	2.5	
Shutdown Current	I_{SHDN}	$V_{IN} = 3.3\text{V}$, $V_{EN} = 0\text{V}$	--	0.1	--	μA
Quiescent Current	I_Q	$V_{IN} = 3.3\text{V}$, $I_{OUT} = 0\text{A}$	--	0.4	--	mA
Line Regulation	ΔV_{LINE}	$I_{OUT} = 10\text{mA}$	--	0.01	--	%/V
Load Regulation	ΔV_{LOAD}	$I_{OUT} = 10\text{mA}$ to 1A , $V_{IN} = 3.3\text{V}$	--	0.5	--	%A
Current Limit	I_{LIM}	$V_{IN} = 3.3\text{V}$	1.05	1.6	--	A
Short-Circuit Current	I_{SC}	$V_{OUT} = 0\text{V}$	--	700	--	mA
Current Foldback Threshold	V_{Fold}	$V_{IN} = 3.3\text{V}$	--	0.4	--	V
Dropout Voltage	V_{DROP}	$I_{OUT} = 1\text{A}$	--	150	300	mV
ADJ Reference Voltage	V_{ADJ}	$V_{IN} = 3.3\text{V}$, $V_{ADJ} = V_{OUT}$, $I_{OUT} = 10\text{mA}$ $T_A = 25^\circ\text{C}$	1.192	1.2	1.216	V
ADJ Current	I_{ADJ}	$V_{IN} = 3.3\text{V}$	--	20	--	nA
Power Supply Rejection Ratio	PSRR	$f = 100\text{Hz}$, $I_{OUT} = 1\text{A}$	--	58	--	dB
		$f = 10\text{kHz}$, $I_{OUT} = 1\text{A}$	--	37	--	
Output Noise Voltage	e_{NO}	$C_{OUT} = 10\mu\text{F}$	--	$27 \times V_{OUT}$	--	μV_{RMS}

Parameter		Symbol	Test Conditions	Min	Typ	Max	Unit
EN Input Voltage	Logic-High	V_{IH}		1.7	--	--	V
	Logic-Low	V_{IL}		--	--	0.5	
EN Input Current		I_{EN}	$V_{IN} = 6V, V_{EN} = 0V$	--	0.02	--	μA
Thermal Shutdown Threshold		T_{SD}		--	160	--	$^{\circ}C$
Thermal Shutdown Hysteresis		ΔT_{SD}		--	30	--	$^{\circ}C$

Note 1. Stresses beyond those listed “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

Note 2. θ_{JA} is measured at $T_A = 25^{\circ}C$ on a high effective thermal conductivity four-layer test board per JEDEC 51-7. θ_{JC} is measured at the exposed pad of the package. The PCB copper area with exposed pad is $70mm^2$.

Note 3. Devices are ESD sensitive. Handling precaution is recommended.

Note 4. The device is not guaranteed to function outside its operating conditions.

Typical Application Circuit

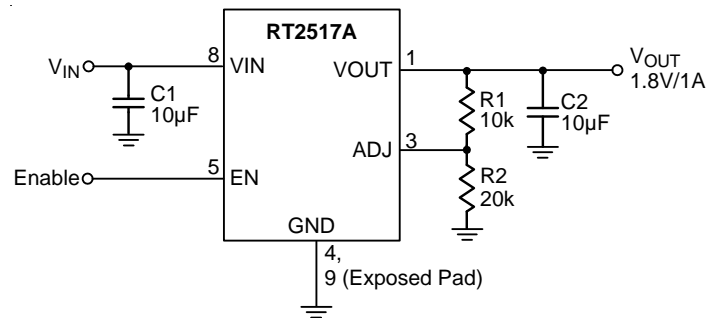
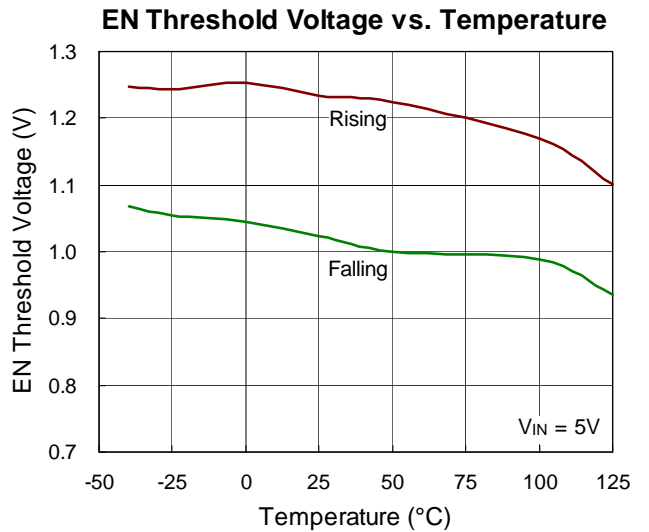
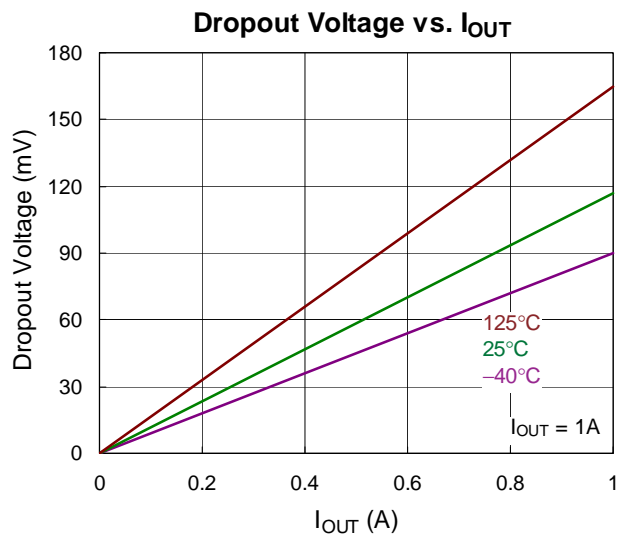
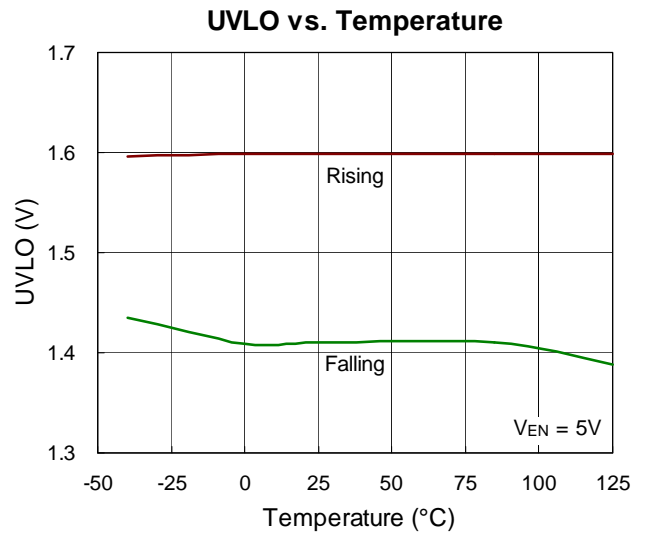
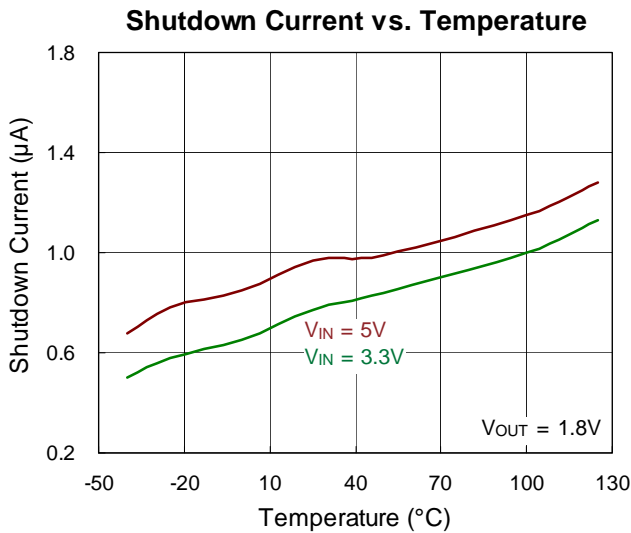
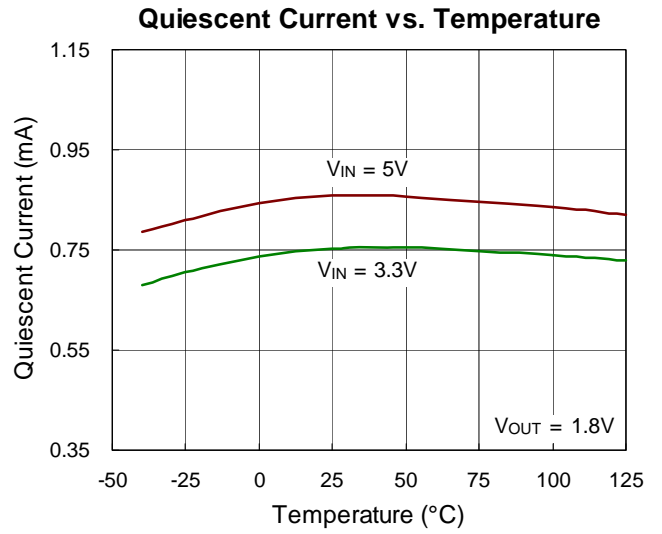
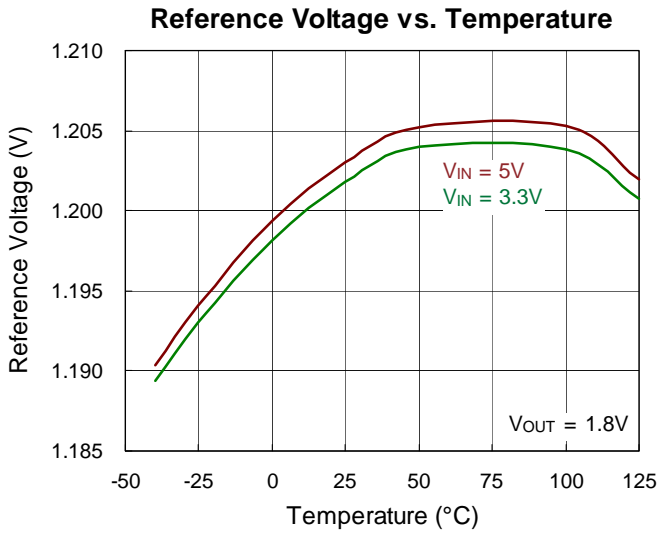
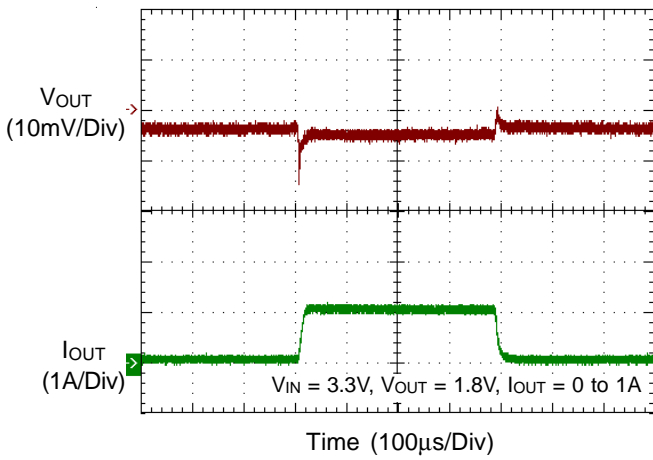


Figure 1. 1.8V Output Voltage Operation Circuit

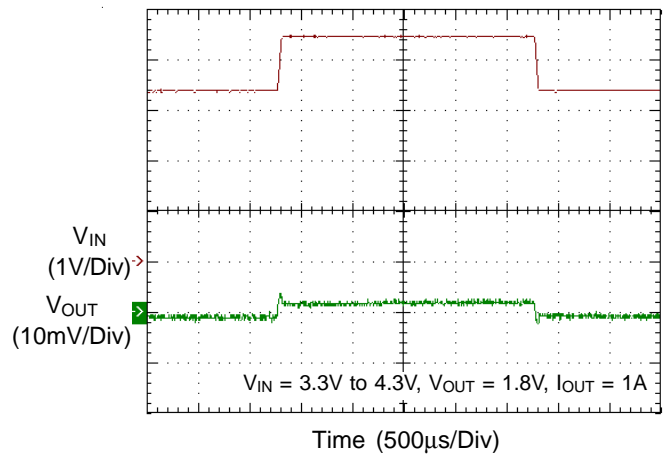
Typical Operating Characteristics



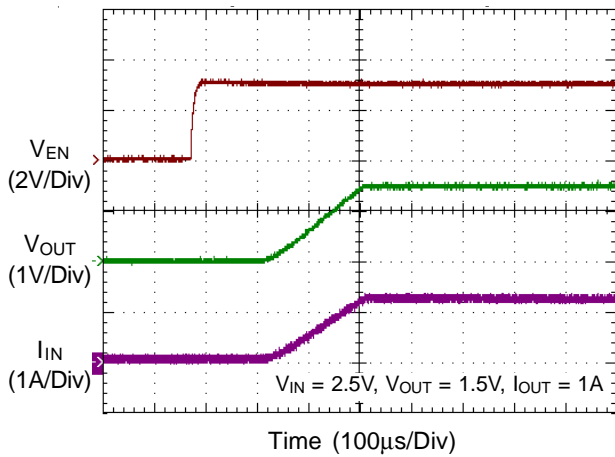
Load Transient Response



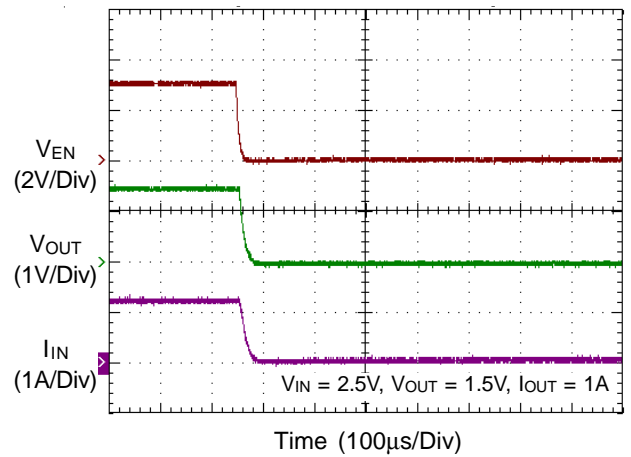
Line Transient Response



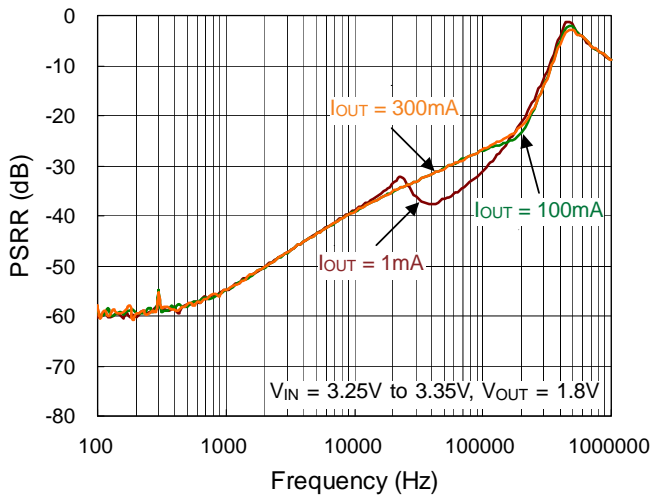
Power On from EN



Power Off from EN



PSRR vs. Frequency



Application Information

The RT2517A is a low voltage, low dropout linear regulator with an external bias supply input capable of supporting an input voltage range from 2.2V to 6V and adjustable output voltage from 1.2V to ($V_{IN} - V_{DROP}$).

Output Voltage Setting

The RT2517A output voltage is adjustable via the external resistive voltage divider. The voltage divider resistors can have values of up to 800kΩ because of the very high impedance and low bias current of the sense comparator. The output voltage is set according to the following equation :

$$V_{OUT} = V_{ADJ} \times \left(1 + \frac{R1}{R2} \right)$$

where V_{ADJ} is the reference voltage with a typical value of 1.2V.

Dropout Voltage

The dropout voltage refers to the voltage difference between the V_{IN} and V_{OUT} pins while operating at specific output current. The dropout voltage V_{DROP} also can be expressed as the voltage drop on the pass-FET at specific output current (I_{RATED}) while the pass-FET is fully operating at ohmic region and the pass-FET can be characterized as an resistance $R_{DS(ON)}$. Thus the dropout voltage can be defined as ($V_{DROP} = V_{IN} - V_{OUT} = R_{DS(ON)} \times I_{RATED}$). For normal operation, the suggested LDO operating range is ($V_{IN} > V_{OUT} + V_{DROP}$) for good transient response and PSRR ability. Vice versa, while operating at the ohmic region will degrade these performance severely.

Chip Enable Operation

The RT2517A goes into sleep mode when the EN pin is in a logic low condition. In this condition, the pass transistor, error amplifier, and band gap are all turned off, reducing the supply current to only 10μA (max.). The EN pin can be directly tied to V_{IN} to keep the part on.

Current Limit

The RT2517A contains an independent current limit circuitry, which controls the pass transistor's gate voltage, limiting the output current to 1.6A (typ.).

C_{IN} and C_{OUT} Selection

Like any low dropout regulator, the external capacitors of the RT2517A must be carefully selected for regulator stability and performance. Using a capacitor of at least 10μF is suitable. The input capacitor must be located at a distance of no more than 0.5 inch from the input pin of the IC. Any good quality ceramic capacitor can be used. However, a capacitor with larger value and lower ESR (Equivalent Series Resistance) is recommended since it will provide better PSRR and line transient response.

The RT2517A is designed specifically to work with low ESR ceramic output capacitor for space saving and performance consideration. Using a ceramic capacitor with capacitance of at least 10μF and ESR larger than 1mΩ on the RT2517A output ensures stability. Nevertheless, the RT2517A can still work well with other types of output capacitors due to its wide range of stable ESR. Figure 2 shows the allowable ESR range as a function of load current for various output capacitance. Output capacitors with larger capacitance can reduce noise and improve load transient response, stability, and PSRR. The output capacitor should be located at a distance of no more than 0.5 inch from the output pin of the RT2517A.

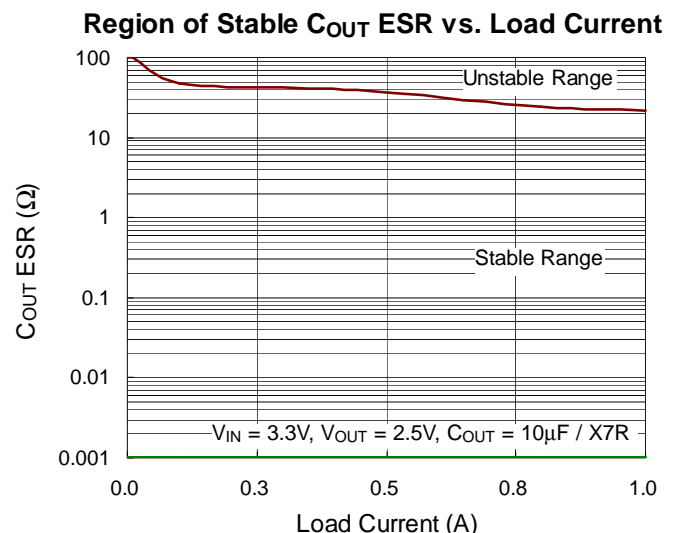


Figure 2.

Thermal Considerations

For continuous operation, do not exceed absolute maximum junction temperature. The maximum power dissipation depends on the thermal resistance of the IC package, PCB layout, rate of surrounding airflow, and difference between junction and ambient temperature. The maximum power dissipation can be calculated by the following formula :

$$P_{D(MAX)} = (T_{J(MAX)} - T_A) / \theta_{JA}$$

where $T_{J(MAX)}$ is the maximum junction temperature, T_A is the ambient temperature, and θ_{JA} is the junction to ambient thermal resistance.

For recommended operating condition specifications, the maximum junction temperature is 125°C. The junction to ambient thermal resistance, θ_{JA} , is layout dependent. For VDFN-8AL 3x3 package, the thermal resistance, θ_{JA} , is 60°C/W on a standard JEDEC 51-7 four-layer thermal test board. The maximum power dissipation at $T_A = 25^\circ\text{C}$ can be calculated by the following formula :

$$P_{D(MAX)} = (125^\circ\text{C} - 25^\circ\text{C}) / (60^\circ\text{C/W}) = 1.667\text{W for VDFN-8AL 3x3 package}$$

The maximum power dissipation depends on the operating ambient temperature for fixed $T_{J(MAX)}$ and thermal resistance, θ_{JA} . The derating curve in Figure 3 allows the designer to see the effect of rising ambient temperature on the maximum power dissipation.

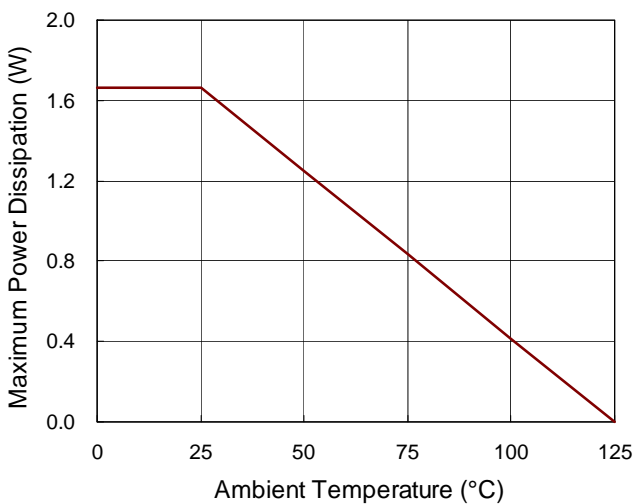
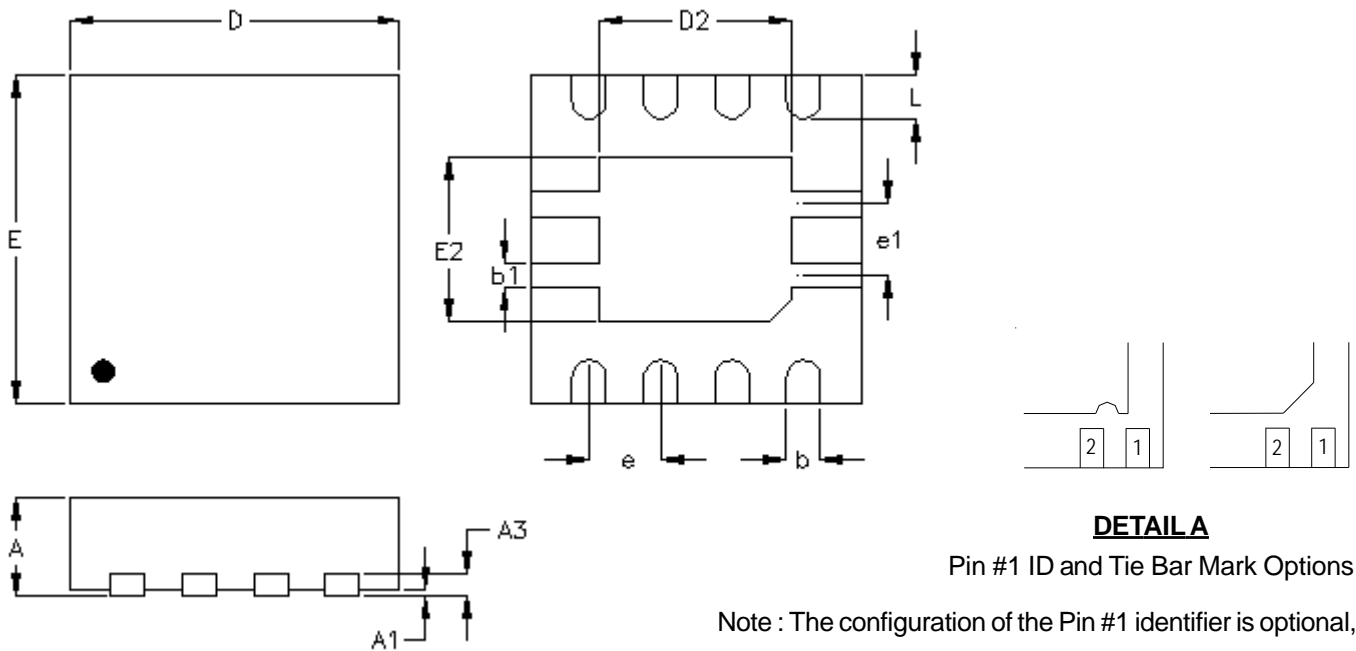


Figure 3. Derating Curve of Maximum Power Dissipation

Outline Dimension



DETAILA
Pin #1 ID and Tie Bar Mark Options

Note : The configuration of the Pin #1 identifier is optional, but must be located within the zone indicated.

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.800	1.000	0.031	0.039
A1	0.000	0.050	0.000	0.002
A3	0.175	0.250	0.007	0.010
b	0.250	0.370	0.010	0.015
b1	0.230		0.009	
D	2.900	3.100	0.114	0.122
D2	1.700	1.800	0.067	0.071
E	2.900	3.100	0.114	0.122
E2	1.450	1.550	0.057	0.061
e	0.650		0.026	
e1	0.650		0.026	
L	0.350	0.450	0.014	0.018

V-Type 8AL DFN 3x3 Package

Richtek Technology Corporation

14F, No. 8, Tai Yuen 1st Street, Chupei City
Hsinchu, Taiwan, R.O.C.
Tel: (8863)5526789

Richtek products are sold by description only. Customers should obtain the latest relevant information and data sheets before placing orders and should verify that such information is current and complete. Richtek cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Richtek product. Information furnished by Richtek is believed to be accurate and reliable. However, no responsibility is assumed by Richtek or its subsidiaries for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Richtek or its subsidiaries.